

SRF Thin Films: Not just for Cavities



21st International Conference on Radio-Frequency Superconductivity

25-30 June 2023

Amway Grand Plaza Hotel

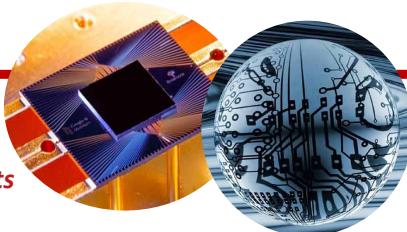
A-M VALENTE-FELICIANO

Outline

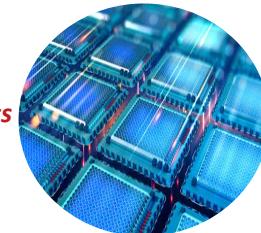


Outline

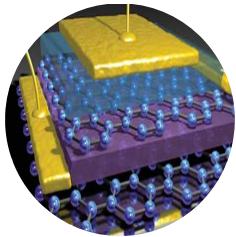
Quantum Systems - Qubits



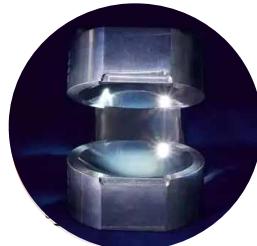
Next Generation Electronics



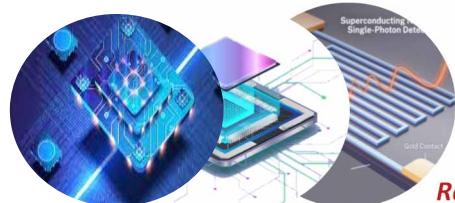
Superconducting Metamaterials



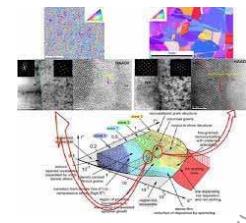
QCD Experiments



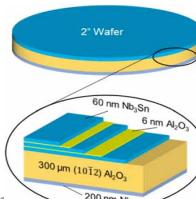
Radiation-hard Sensing



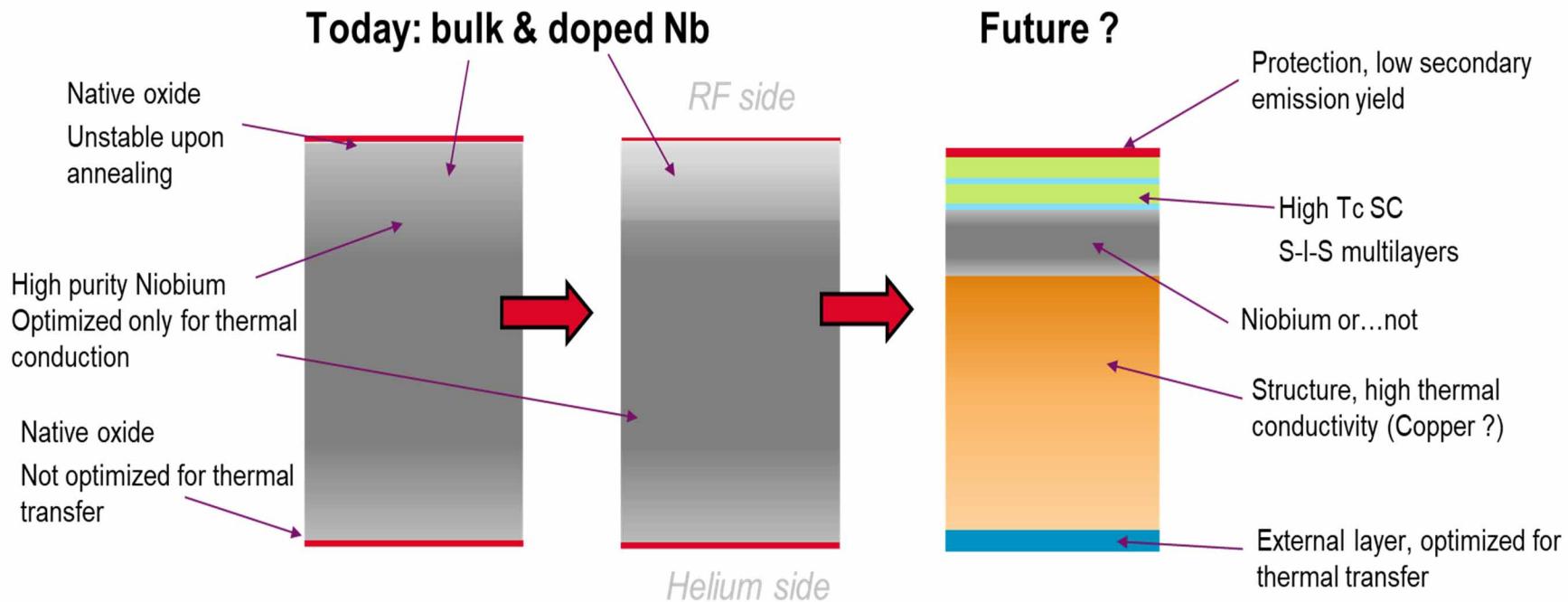
SRF Ancillaries



SRF Thin Films



SRF Thin Films for Next-Generation Cavities



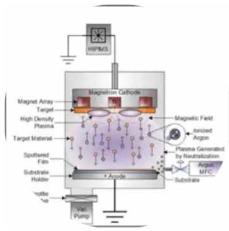
Courtesy C. Antoine

MOTIVATION

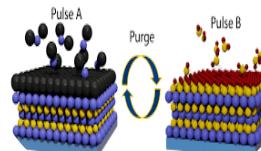
- Recent years have seen renewed interest and activities in developing SRF cavity materials based on thin film technologies.



ECR



HiPIMS



ALD

- Beyond cavity applications, the developments in SRF thin film technologies find a variety of applications in the fields of superconducting metamaterials, electronics, sensors and quantum devices.
- Unifying theme across these technologies is that the same physics and material properties such as extreme low loss, stability, and manufacturability are required.**



ANCILLARIES FOR ACCELERATORS

3D Cu printed ancillaries with improved cooling with ECR, HiPIMS or ALD coatings (Nb, NbTiN, Nb₃Sn....)



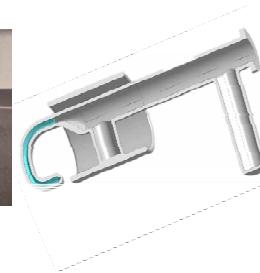
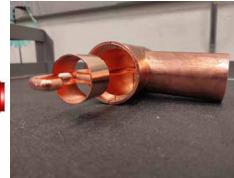
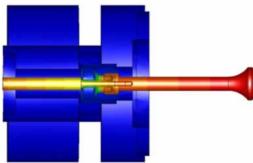
C. Ledford, NCSU

HOM Probe coating with Nb₃SN or NbTiN
on Nb/Cu Antennas – P. Plattner, Helmholtz-Institut Mainz, TFSRF2022



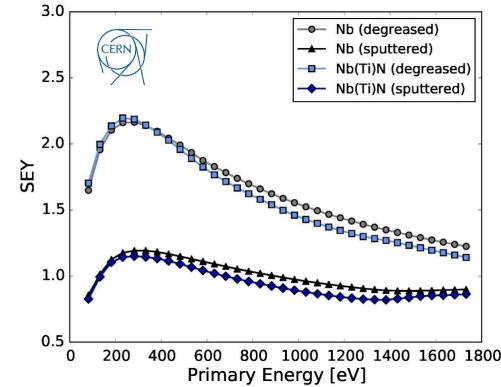
ANCILLARIES FOR ACCELERATORS

3D Cu printed ancillaries with improved cooling with ECR, HiPIMS or ALD coatings (Nb, NbTiN, Nb₃Sn....)



C. Ledford, NCSU

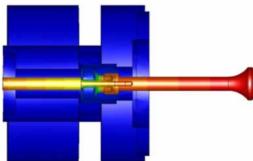
HOM Probe coating with Nb₃Sn or NbTiN
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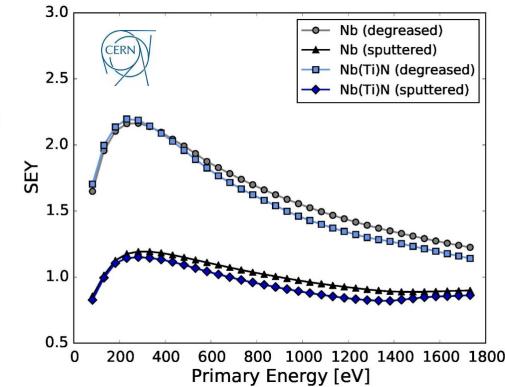
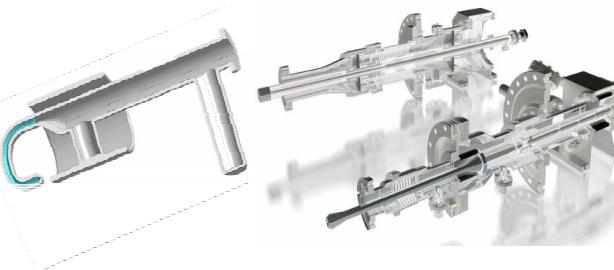


ANCILLARIES FOR ACCELERATORS

3D Cu printed ancillaries with improved cooling with ECR, HiPIMS or ALD coatings (Nb, NbTiN, Nb₃Sn....)



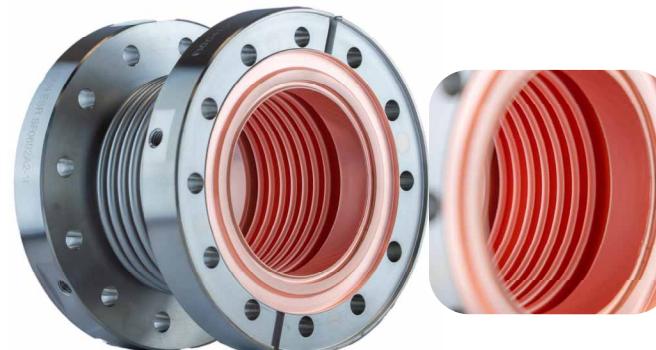
C. Ledford, NCSU



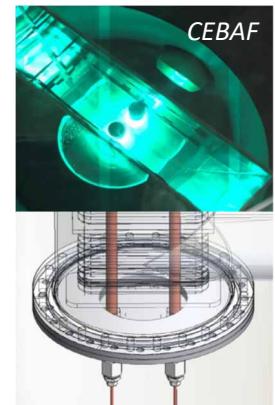
HOM Probe coating with Nb₃SN or NbTiN
on Nb/Cu Antennas – P. Plattner, Helmholtz-Institut Mainz, TFSRF2022

HiPIMS application to Cu on stainless steel bellows
without Ni strike layer

*Reliable, reproducible method, improved
aspect ratio on convolutions*

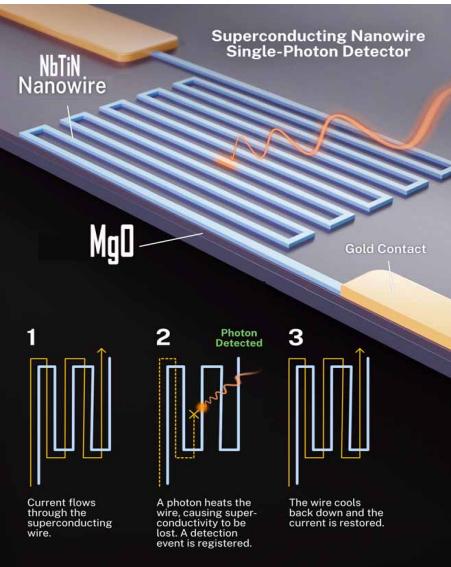


SBIR-II project, Starfire & JLab

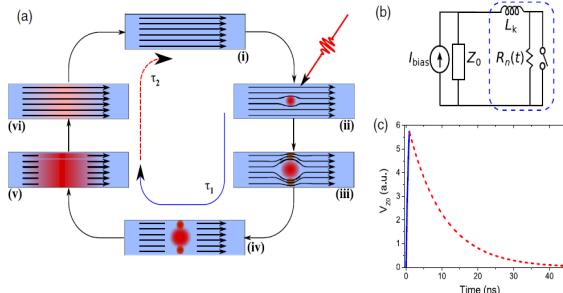




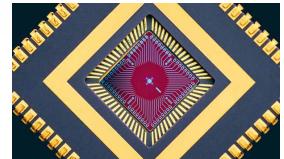
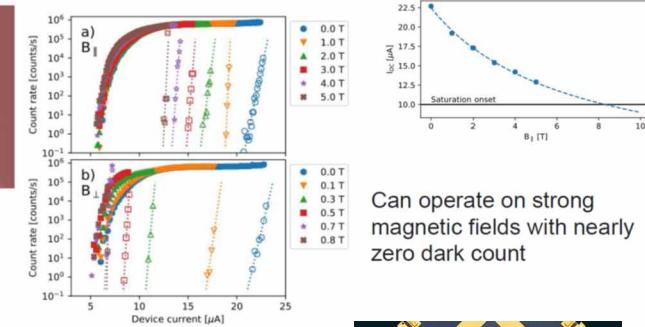
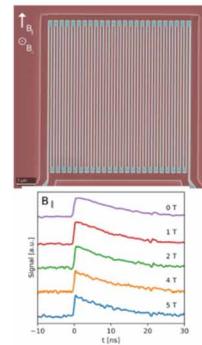
Radiation Hard Detectors



Chandra M Natarajan et al 2012 *Supercond. Sci. Technol.* **25** 063001



Highest performing detectors available from the ultraviolet to the mid-infrared



Matt Shaw, JPL

- EIC-related Detector R&D, Active Polarized Neutron Target Concept for CLAS12, Superconducting Magnet integrated particle detector, rapid SFQ electronics, beam loss monitors....
- Optical communications (large mid-IR focal plane arrays of SNSPD for exoplanet transit spectroscopy for the Origins Space Telescope. UV SNSPD are being integrated with ion trap chips for quantum computing applications.

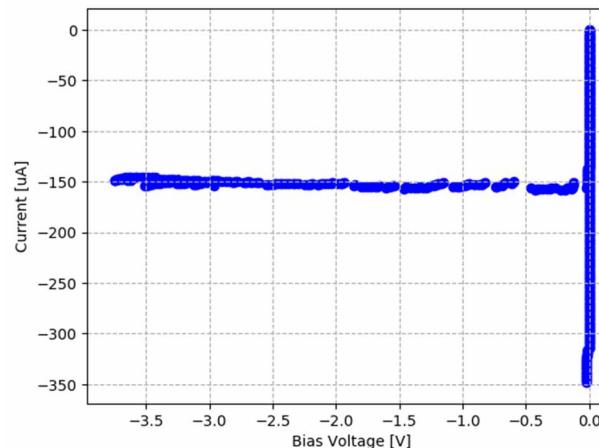
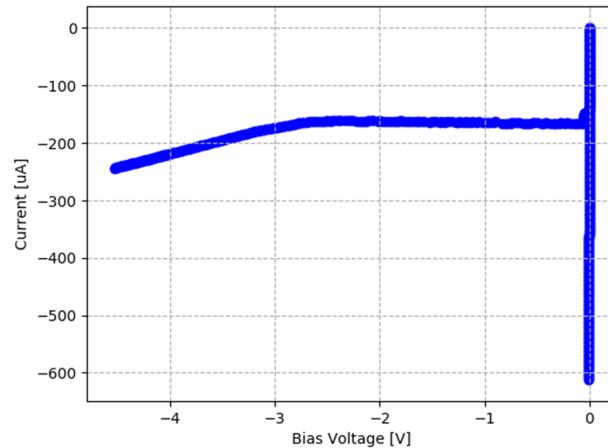
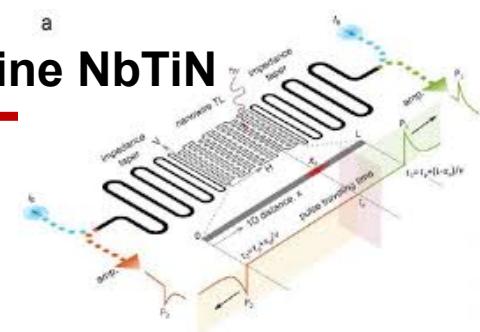


SNSPD Applications - Preliminary Results with crystalline NbTiN

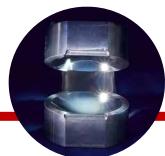
- SNSPD patterned from 10 nm thick film
 - $T_c = 14.15 \pm 0.5$ K
 - Too thick yet to be photon sensitive



M.D. Shaw, A.D. Beyer, B.A. Korzh, B. Bubbler

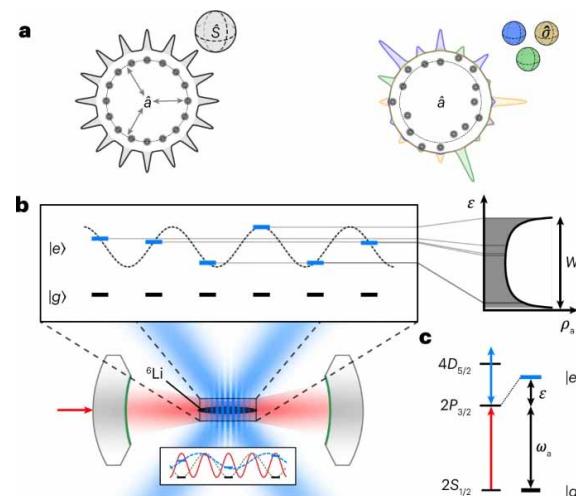
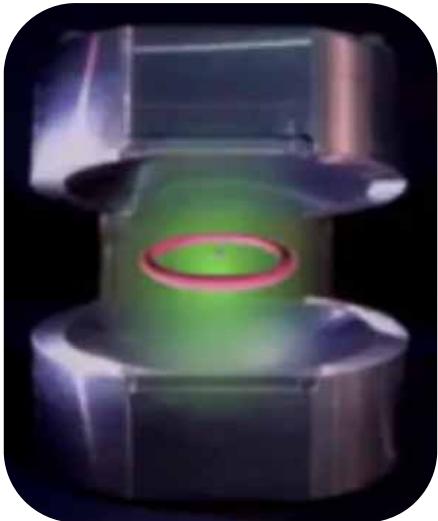


*switching current of 300 μ A (~30 higher than usual JPL NbTiN recipe), re-trapping current of 150 μ A
Open the way to detection without amplification*



QCD Experiments

High-finesse, near-concentric optical resonator enables strong and long-range interactions among atomic spins.



ECR Nb/Cu, 180 eV nucleation



STANFORD



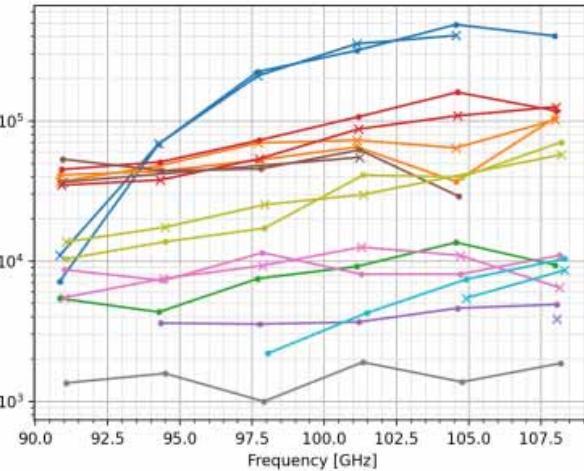
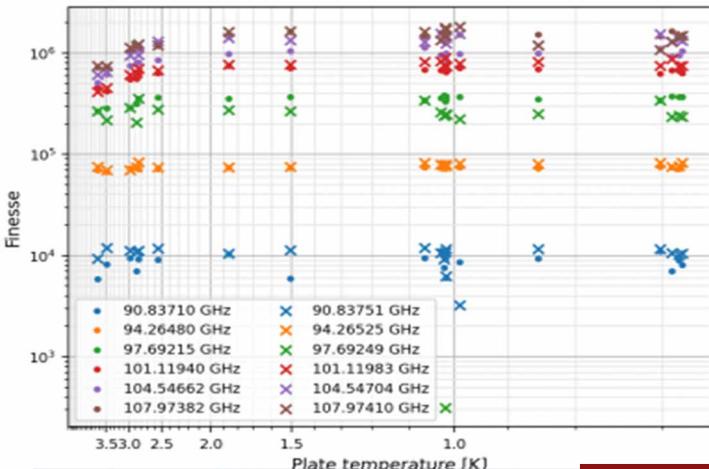
D. Vitali, et al., *Journal of Modern Optics*, 54:11, 1551-1567 .(2007)
Haroche, S., Brune, M. & Raimond, J.M. *Nat. Phys.* 16, 243–246 (2020)



ECR Nb Films for Studies of Highly Entangled States of Laser-Cooled Atoms



High-finesse measurements in near-confocal Fabry–Perot geometry enable strong and long-range interactions among atomic spins



Polarization	Center frequency (GHz)	Linewidth (kHz)	<i>Q</i>	Finesse
s	107.97381668(2)	2.3(1)	46.9(2.0) M	1.49(6) M
p	107.97422315(5)	2.15(20)	50(5) M	1.59(15) M

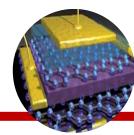
At 4.2 K, TEM00 modes improved with frequency, suggesting limitation by diffractive loss.
 At 700 mK, TEM00 modes barely improved, modest improvement for higher frequency ones
 Best modes : 2 orthogonal polarizations of TEM(31, 0, 0) at 107.974 MHz, with $Q \sim 5 \times 10^7$

Courtesy T. Zhang, M. Schleier-Smith et al.



STANFORD

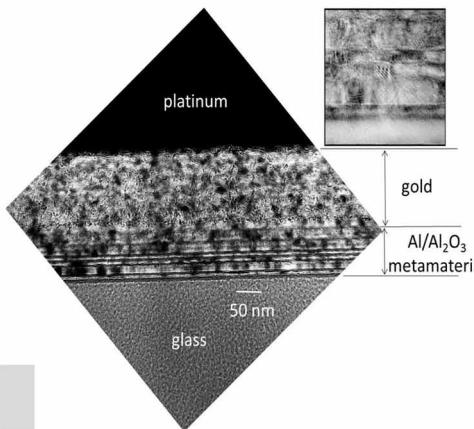
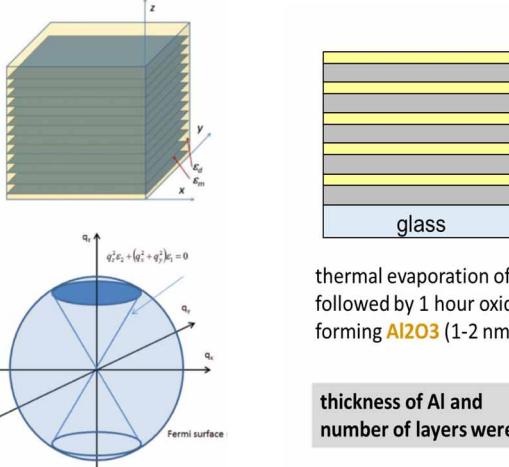
SLAC
NATIONAL ACCELERATOR LABORATORY



Metamaterials Developments

Meta-materials for functional surfaces

Nature Scientific Reports 6, Article number: 34140 (2016)

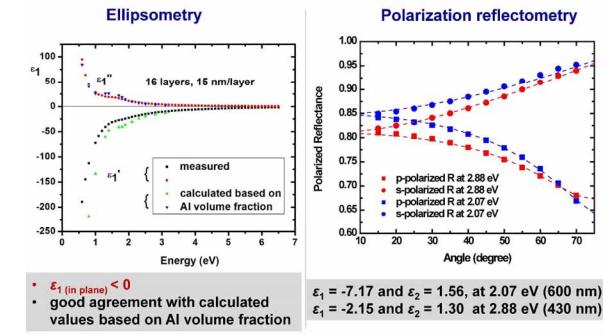


Applications: compact RF resonator application, THz SIS Receivers, RF-SQUID arrays, MRI (magnetic resonance imaging) and near field imaging

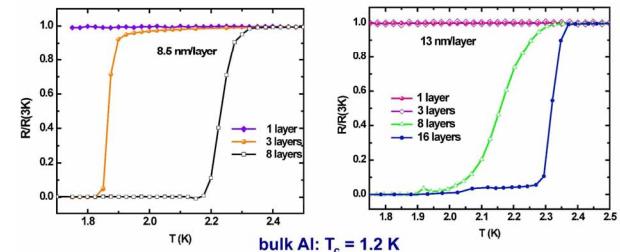
For example, Metamaterials on MgB₂ could get superconducting structures at LN₂ temperatures

Materials Research Foundations 132 (2022) 194-210

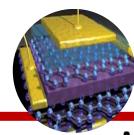
Hyperbolic character of Al/Al₂O₃ multilayers
 $(\epsilon_1 \text{ (in plane)} < 0; \epsilon_2 \text{ (out of plane)} > 0)$



Effect of the number of layers on T_c of the Al/Al₂O₃ hyperbolic metamaterial samples



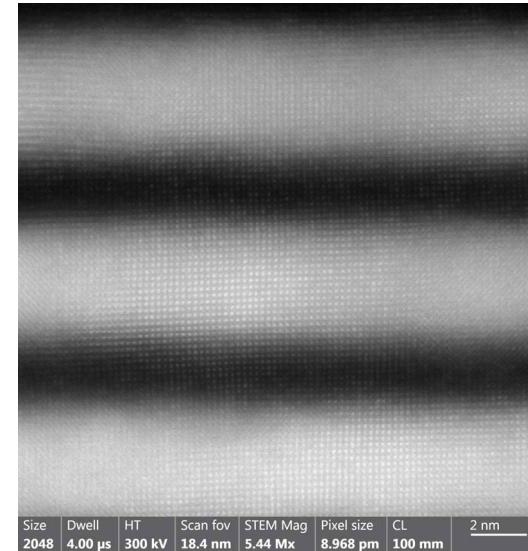
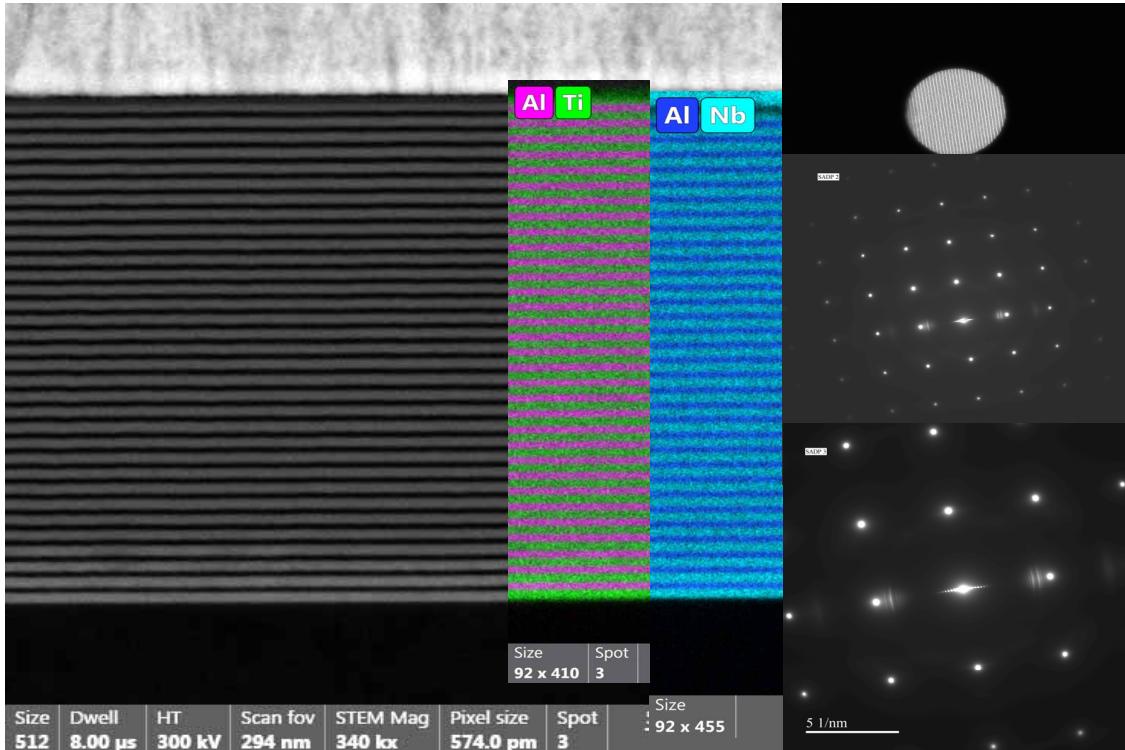
Metamaterial (multilayer) is needed for T_c enhancement

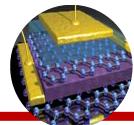


Metamaterials based on NbTiN

Meta-materials for functional surfaces

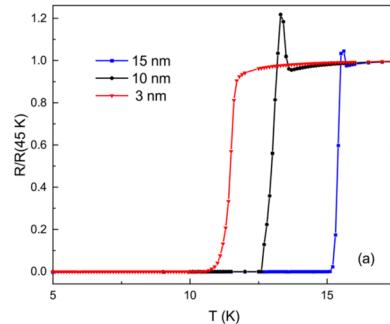
- Multilayer structure of NbTiN = 3.6/3/2 nm and AlN = 2/1.5/1 nm.
N bilayers deposited on NbTiN/MgO



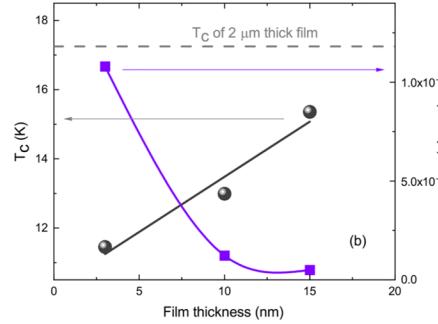


NbTiN/AlN Metamaterials Developments

Effect of Thickness on Critical Temperature

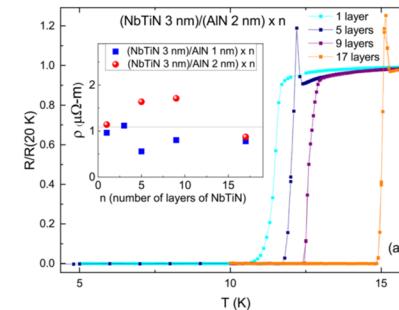


Normalized temperature dependence of the resistance of standalone NbTiN films as a function of thickness.

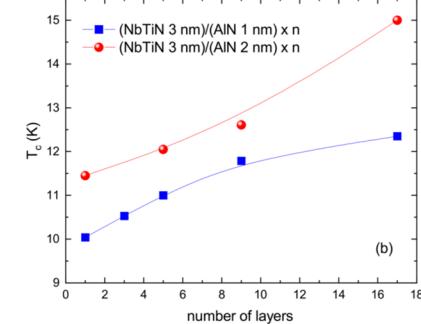


Thickness dependence of T_c and resistivity at $T = 20\text{ K}$ for the standalone films (lines are guides for the eye).

Effect of Number of Layers on Critical Temperature

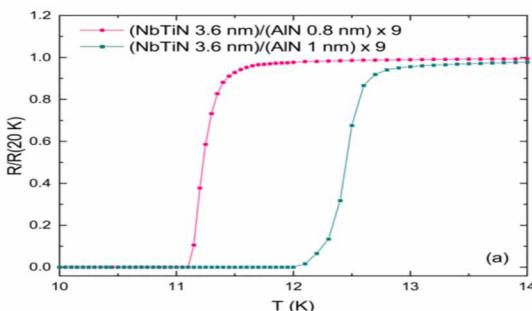


Normalized temperature dependence of the resistance of $(\text{NbTiN } 3\text{ nm})/(\text{AlN } 2\text{ nm}) \times n$ films for the varying number of layers, n . The inset shows the resistivity of $(\text{NbTiN } 3\text{ nm})/(\text{AlN } 2\text{ nm}) \times n$ and $(\text{NbTiN } 3\text{ nm})/(\text{AlN } 1\text{ nm}) \times n$ multilayers as a function of n . The dashed line is the average resistivity of the multilayers, $1.1\text{ }\Omega\text{-m}$.

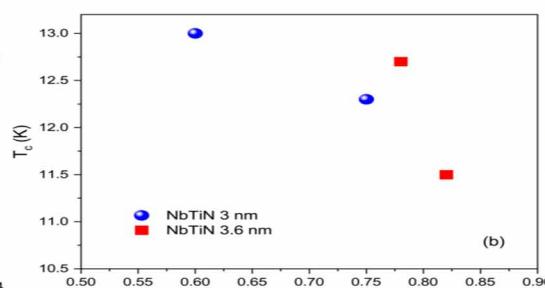


Dependence of the T_c on n for $(\text{NbTiN } 3\text{ nm})/(\text{AlN } 2\text{ nm}) \times n$ and $(\text{NbTiN } 3\text{ nm})/(\text{AlN } 1\text{ nm}) \times n$ multilayers. The T_c of these metamaterials is up to 32% higher than the T_c of a single ultrathin NbTiN layer (lines to guides the eye).

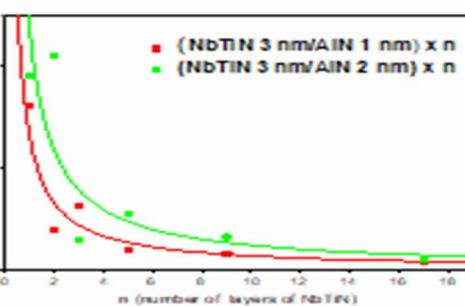
Effect of Volume Fraction of the Metal



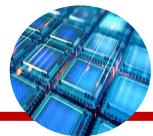
Normalized temperature dependence of the resistance of the $(\text{NbTiN } 3.6\text{ nm})/(\text{AlN } 0.8\text{ nm}) \times 9$ and $(\text{NbTiN } 3.6\text{ nm})/(\text{AlN } 1\text{ nm}) \times 9$ films, which have different volume fractions of metal.



T_c dependence on the volume fraction of metal for the 8 bi-layer NbTiN/AlN structures.



Jefferson Lab



Superconducting Digital Logic

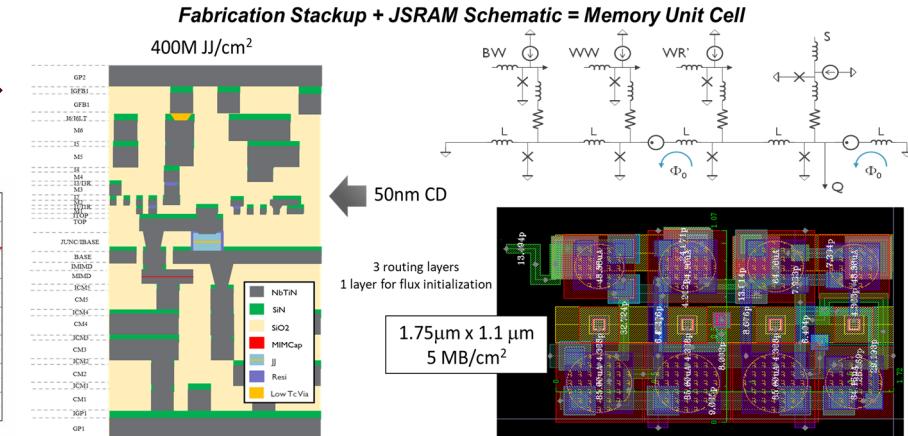
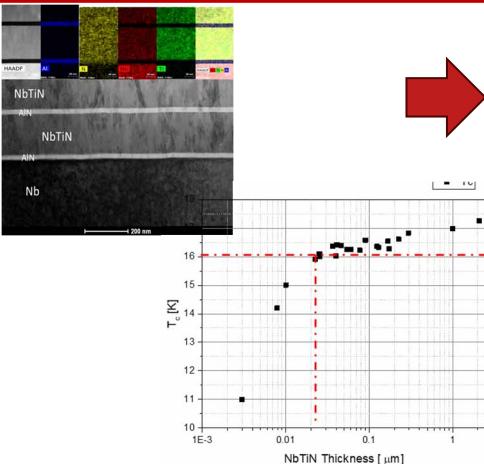
imec



Jefferson Lab



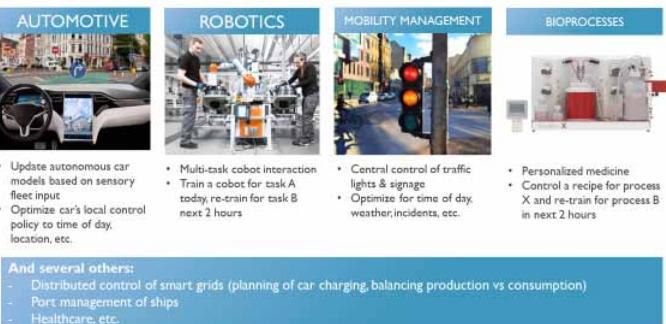
CMOS	7 nm	Superconducting
		30 nm
Speed	1.4 GHz	17x
Memory	500 MB/cm ² (SRAM)	0.01x
Device density	1T devices/cm ²	0.1x
Interconnects	1.6 Gb/line @ 1 pJ/bit	120x, 1000x
Power efficiency	1 TOPS/W	50x



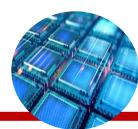
- Fabrication stackup for digital logic with 16 superconducting NbTiN layers, self-shunted α -silicon barrier Josephson Junctions (JJs), and low loss, high- k tunable HZO capacitors to enable 400 MJJ/cm^2 device density
- Energy efficiency, high computational density, and high interconnect bandwidth.
- Uniquely enable real-time AI training models and improved security by distributing to edge systems compute power that currently must be deployed in a centralized data center

Potential to provide a sustainable solution for large-scale compute applications positioned between mature CMOS and long-horizon quantum computing.

ACTIVE CONTROL AT THE EDGE HAS SEVERAL APPLICATIONS



Courtesy Q. Herr, imec

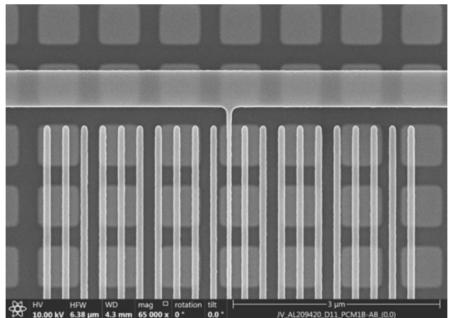


Superconducting Digital Logic

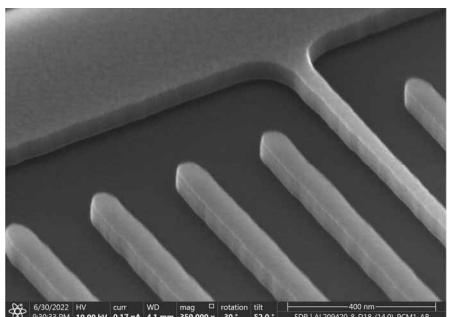
imec



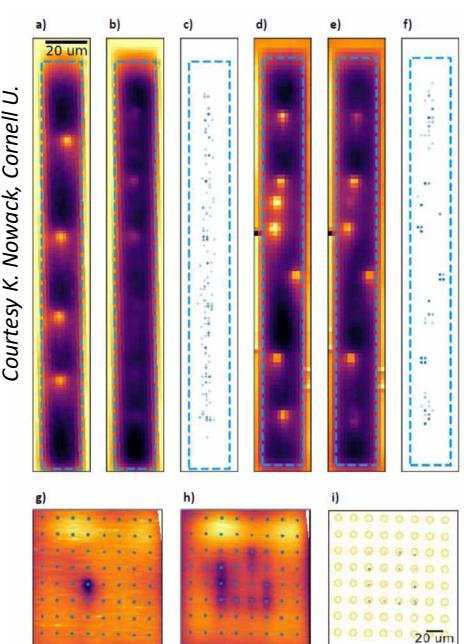
Jefferson Lab



2 metal layers with 50 nm critical dimension.

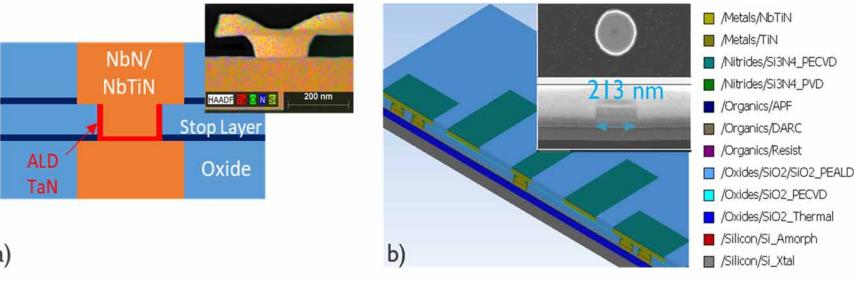


Courtesy A. Herr, imec

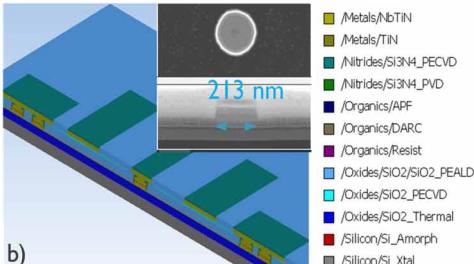


Magnetic imaging of field-cooled patterned NbTiN ground planes showing vortex location.

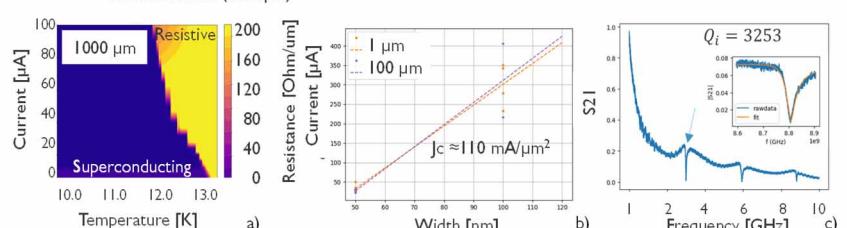
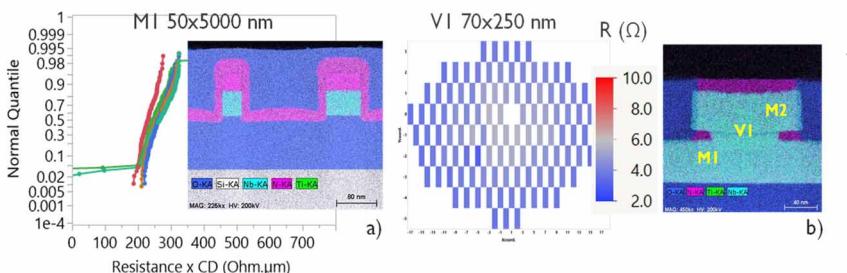
20 mm strip fabricated from a 100 nm thick film cooled in 12 -14 μT fields.



a)



b)



$T_c = 12.5 \text{ K}$

$j_c = 110 \text{ mA}/\mu\text{m}^2 @ 4.2 \text{ K}$

Jefferson Lab



Quantum Information Systems

QIS NP Funding

Jefferson Lab



Fermilab

within



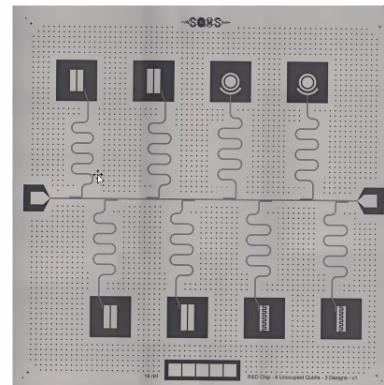
**SUPERCONDUCTING QUANTUM
MATERIALS & SYSTEMS CENTER**

Exploit JLab high quality films deposited by ECR for qubit optimization

- Optimization of Nb/Al₂O₃ films in the thickness range of 150-200 nm specific for qubits
- Development and optimization of Nb/Si
- Investigation of other superconducting materials
- Optimization of transmon & flux qubits coherence time
- Optimization of 2D and 3D design concepts

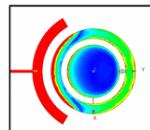
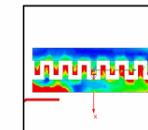
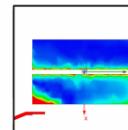


2D SQMS R&D Qubit Chip – v1

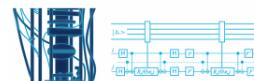


Standardized qubit chip

- 8 fixed frequency uncoupled transmons ~ 4 – 5 GHz
 - 4 w/ double capacitive pads (for statistics)
 - 2 w/ interdigitated capacitive pads (most sensitive)
 - 2 w/ concentric capacitive pads (most insensitive)
- Anharmonicity ~ 220 MHz
- Readout resonators ~ 6 – 8 GHz
- Frequency multiplexing on single feedline



E-field distribution of different transmon geometries

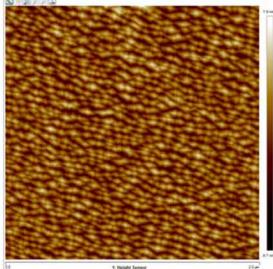




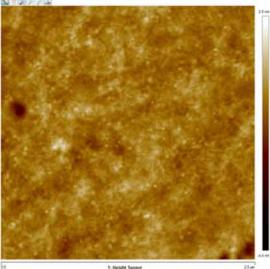
High quality Nb films for Qubits

150 - 200 nm ECR Nb films nucleated at 304 eV, subsequent growth at 64 eV

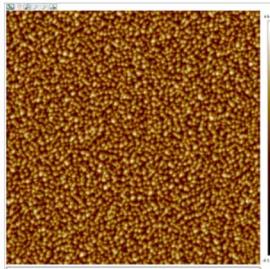
Nb/ Al₂O₃ (11-20)



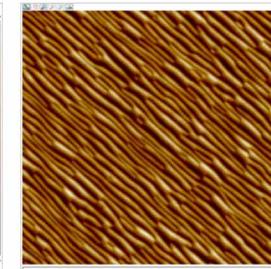
Nb/ Al₂O₃ (0001)



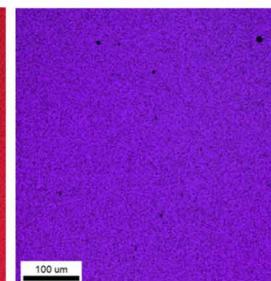
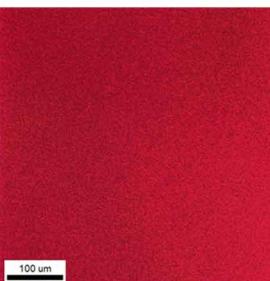
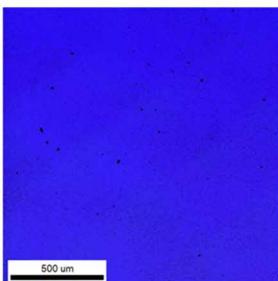
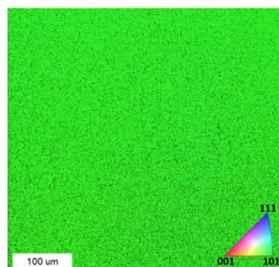
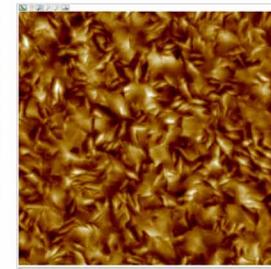
Nb/ Al₂O₃ (1-120)



Nb/ Al₂O₃ (10-10)



Nb/ fused silica

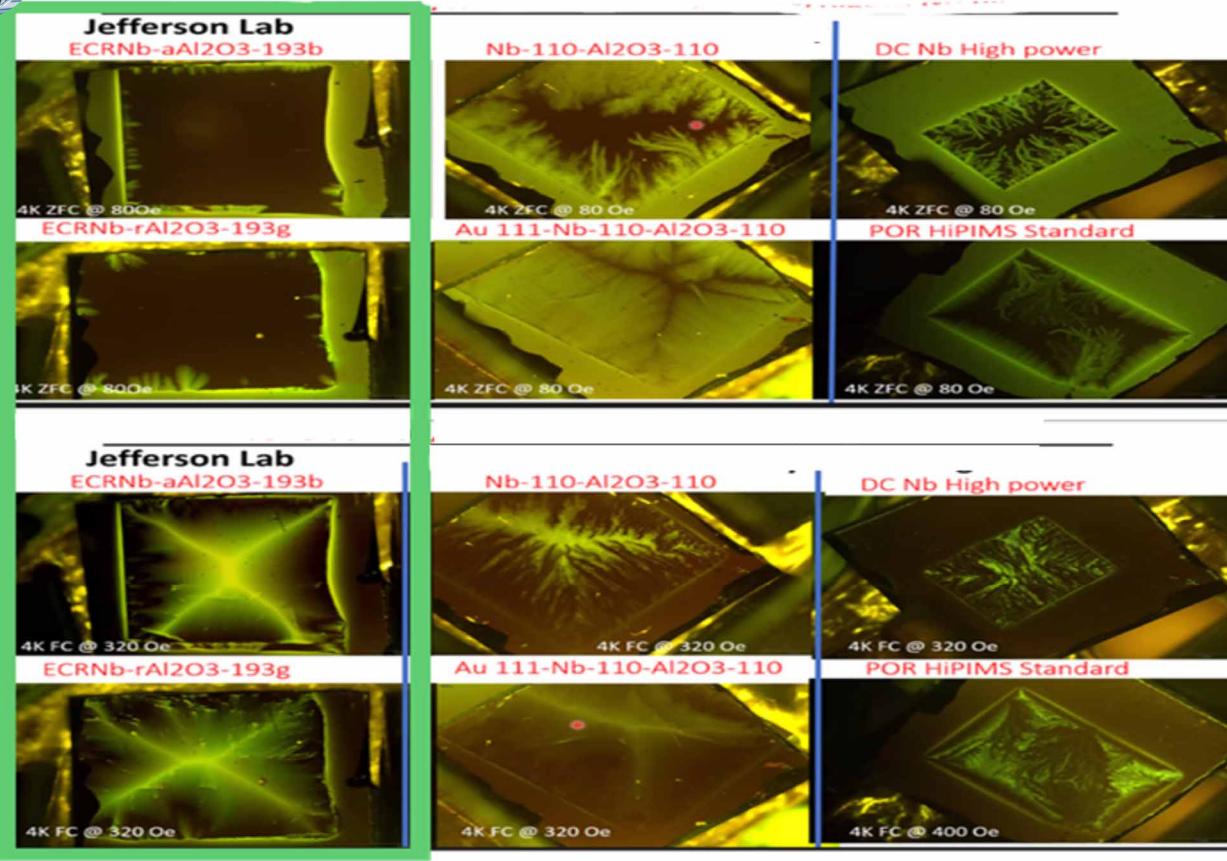


R _a [nm]	Al ₂ O ₃				Fused Silica	
	(11-20)	(0001)	(1-120)	(10-10) ceramic		
2 um	1.54	0.28	1.03	1.35	1.81	
5 um	1.52	0.34	1	1.31	1.86	
10 um	1.5	0.47	0.89	1.17	1.84	
50 um	0.95	0.55	0.66	0.46	1.69	
T _c [K]	9.33	9.33	9.32	9.28	9.29	9.24
ΔT _c [K]	0.07	0.06	0.04	0.05	0.06	0.26
RRR	75.60	79.00	83.00	68.00	39.00	14.00

Preliminary work : collaboration with JLab, FNAL, Ames Lab, Temple University



High quality Nb films for Qubits



Magneto-optical Measurements

R. Prozorov et al (Ames)



SUPERCONDUCTING QUANTUM
MATERIALS & SYSTEMS CENTER

Preliminary

SUMMARY

Many Applications of SRF Thin Films beyond Cavities :

Ancillaries, Metamaterials, Novel Electronics and Sensors, Quantum Devices

Developments of high performing, low-loss SRF Thin Films

- Truly synergistic with benefits for both SRF and Applications*
- Allow more in-depth studies or out-of-the box developments*
- Potential for transformational developments with benefits for society at large*